

# isc N-Channel MOSFET Transistor

# 2SK3822B

## **FEATURES**

• Drain Current : I<sub>D</sub>= 52A@ T<sub>C</sub>=25℃

- Drain Source Voltage
  - : V<sub>DSS</sub>= 100V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 25m \Omega (Max) @V_{GS} = 10V$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### **DESCRIPTION**

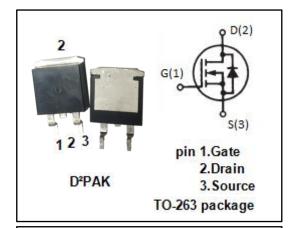
 motor drive, DC-DC converter, power switch and solenoid drive.

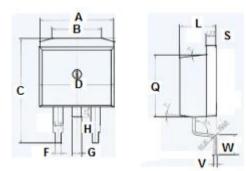
## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	100	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±20	V
I <sub>D</sub>	Drain Current-Continuous	52	А
I <sub>DM</sub>	Drain Current-Single Pluse	208	А
P <sub>D</sub>	Total Dissipation @Tc=25℃	75	W
TJ	Max. Operating Junction Temperature	-55~150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~150	${\mathbb C}$

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	1.67	°C/W





DIM	m	m
DIIVI	MIN	MAX
Α	9.8	10.2
В	6.6	6.8
C	15.1	15.3
D	9.6	10
F	0.7	0.9
G	1.26	1.3
Н	1.2	1.45
L	4.4	4.6
Q	9.2	9.3
S	1.25	1.35
V	0.4	0.6
W	2.6	2.8

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### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 1mA	100		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> = 1mA	1.2	2.6	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 26A V <sub>GS</sub> = 4V; I <sub>D</sub> = 26A		25 32	m Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±16V;V <sub>DS</sub> =0	I	±10	uA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 100V; V <sub>GS</sub> = 0	1	1.0	uA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 52A; V <sub>GS</sub> = 0	1	1.5	V

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